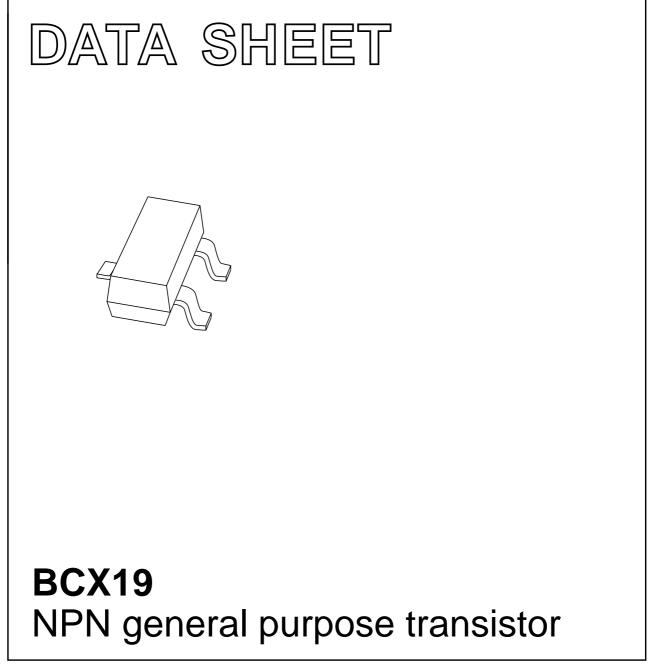
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 2000 Jul 28 2004 Jan 16



NPN general purpose transistor

FEATURES

- High current (500 mA)
- Low voltage (45 V).

APPLICATIONS

- General purpose amplification
- Saturated switching and driver applications.

DESCRIPTION

NPN transistor in a SOT23 plastic package. PNP complement: BCX17.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾		
BCX19	U1*		

Note

1. * = p : Made in Hong Kong.

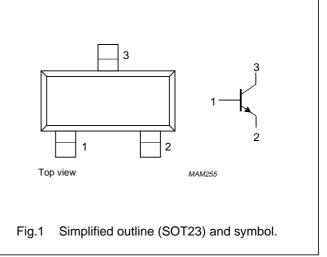
* = t : Made in Malaysia.

* = W : Made in China.

ORDERING INFORMATION

PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



ТҮРЕ		PACKAGE			
NUMBER	NAME	DESCRIPTION VERSION			
BCX19	_	plastic surface mounted package; 3 leads	SOT23		

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base; I _C = 10 mA	-	45	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current (DC)		-	500	mA
I _{CM}	peak collector current		-	1	A
I _{BM}	peak base current		-	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

BCX19

NPN general purpose transistor

BCX19

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 20 V	-	-	100	nA
		I _E = 0; V _{CB} = 20 V; T _j = 150 °C	-	-	5	μA
I _{EBO}	emitter cut-off current	I _C = 0; V _{EB} = 5 V	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 1 V; note 1				
		I _C = 100 mA	100	-	600	
		I _C = 300 mA	70	-	-	
		I _C = 500 mA	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C}$ = 500 mA; $I_{\rm B}$ = 50 mA; note 2	-	-	620	mV
V _{BE}	base-emitter voltage	$I_C = 500 \text{ mA}; V_{CE} = 1 \text{ V}; \text{ notes 1 and 2}$	_	_	1.2	V
C _c	collector capacitance	I _E = I _e = 0; V _{CB} = 10 V; f = 1 MHz	_	5	-	pF
f _T	transition frequency $I_{C} = 10 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz}$		100	_	_	MHz

Notes

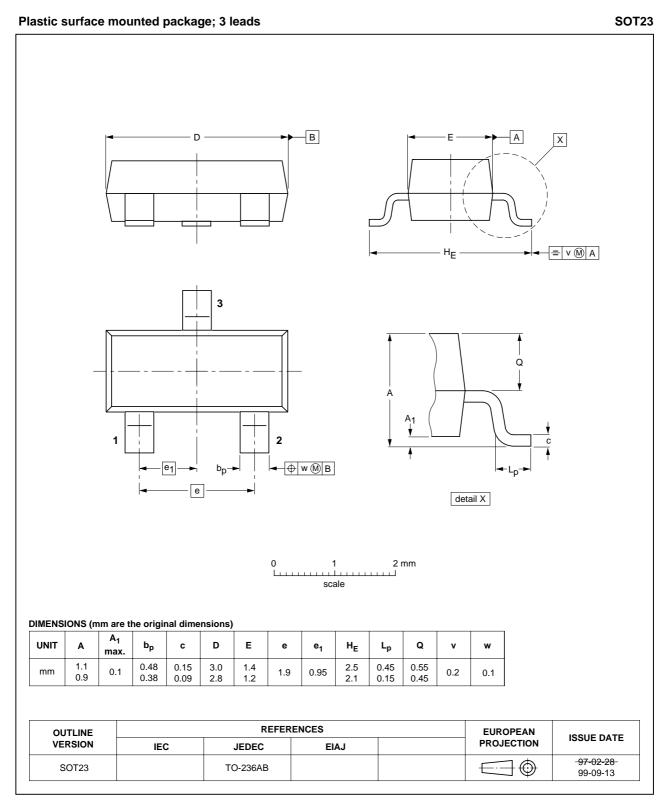
1. Pulse test: $t_p \leq 300 \ \mu s; \ \delta \leq 0.02.$

2. V_{BE} decreases by approximately $-2 \text{ mV/}^{\circ}C$ with increasing temperature.

BCX19

NPN general purpose transistor

PACKAGE OUTLINE



NPN general purpose transistor

BCX19

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
1	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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